

**Notice of References Cited**

Application/Control No.

10/082,965

Applicant(s)/Patent Under  
Reexamination  
IMAI ET AL.

Examiner

Kallambella Vijayakumar

Art Unit

1751

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	W	Amara et al, "Thermoelectric Power of TiS <sub>2</sub> ", Physical Review-B, 1987, 36(12), pp 6415-6419.
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Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.